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# BLF7G27L-100; BLF7G27LS-100 Power LDMOS transistor

**AMPLEON** 

Rev. 5 — 1 December 2016

Product data sheet

## **Product profile**

#### 1.1 General description

100 W LDMOS power transistor for base station applications at frequencies from 2500 MHz to 2700 MHz.

**Typical performance** Table 1.

Typical RF performance at  $T_{case} = 25$  °C in a common source class-AB production test circuit.

Mode of operation	f	$I_{Dq}$	V <sub>DS</sub>	P <sub>L(AV)</sub>	Gp	$\eta_D$	ACPR <sub>885k</sub>	ACPR <sub>5M</sub>
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
IS-95	2500 to 2700	900	28	20	18	28	-45 <mark>[1]</mark>	-
Single carrier W-CDMA	2500 to 2700	900	28	25	17.5	30	-	-41 <sup>[2]</sup>

<sup>[1]</sup> Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

#### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R<sub>th</sub> providing excellent thermal stability
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 2500 MHz to 2700 MHz frequency range.

<sup>[2] 3</sup>GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

## 2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF7G27	7L-100 (SOT502A)			
1	drain			_
2	gate			
3	source	[1]		2 — 3 3 sym112
BLF7G27	7LS-100 (SOT502B)			-
1	drain			
2	gate		1   3	
3	source	<u>[1]</u>	2	2 - 3 sym112

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLF7G27L-100	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A		
BLF7G27LS-100	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B		

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Cyllibol	T drameter	Conditions	141111	IVIUX	Oilit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
I <sub>D</sub>	drain current		-	28	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_{L}$ = 100 W	0.25	K/W

BLF7G27L-100\_7G27LS-100

#### 6. Characteristics

#### Table 6. Characteristics

 $T_i$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 153 mA	1.5	1.8	2.3	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	5	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	25.1	29	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	500	nA
g <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 153 mA	-	1.34	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5.35 \text{ A}$	-	0.1	-	Ω

#### 7. Test information

Remark: All testing performed in a class-AB production test circuit.

#### Table 7. Functional test information

Mode of operation: 1-carrier N-CDMA, single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF, channel bandwidth is 1.2288 MHz;  $f_1$  = 2500 MHz;  $f_2$  = 2700 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA;  $T_{case}$  = 25 °C; unless otherwise specified.

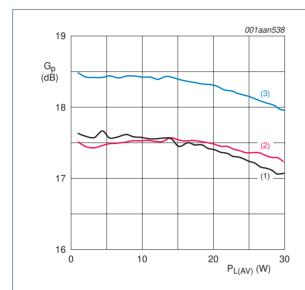
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	20	-	W
$G_p$	power gain		16.3	18	-	dB
RLin	input return loss		-	-10	-	dB
$\eta_{D}$	drain efficiency		24	28	-	%
ACPR <sub>885k</sub>	adjacent channel power ratio (885 kHz)		-	<del>-45</del>	-40	dBc

#### 7.1 Ruggedness in class-AB operation

The BLF7G27L-100 and BLF7G27LS-100 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 28 \text{ V}$ ;  $I_{Dq} = 900 \text{ mA}$ ;  $P_L = 100 \text{ W}$  (CW); f = 2500 MHz.

#### 7.2 Single carrier IS-95

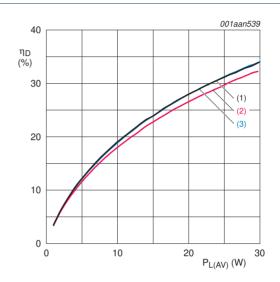
Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

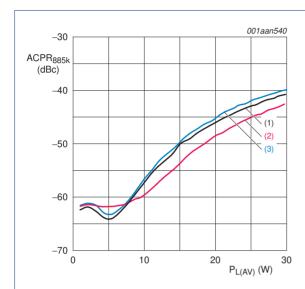
Fig 1. Single carrier IS-95 power gain as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Da}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

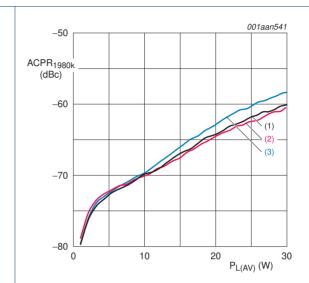
Fig 2. Single carrier IS-95 drain efficiency as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

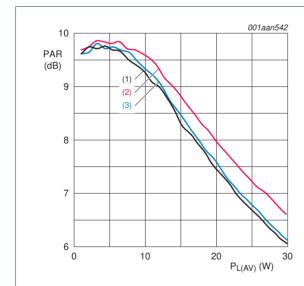
Fig 3. Single carrier IS-95 ACPR at 885 kHz as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

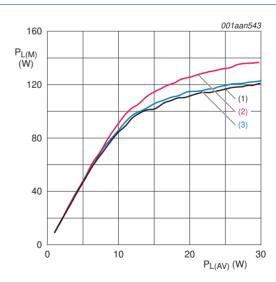
Fig 4. Single carrier IS-95 ACPR at 1980 kHz as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Fig 5. Single carrier IS-95 peak-to-average power ratio as a function of average output power; typical values

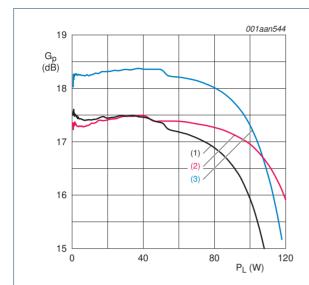


 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Fig 6. Single carrier IS-95 peak output power as a function of average output power; typical values

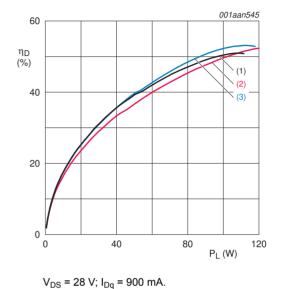
#### 7.3 Pulsed CW



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Pulsed CW power gain as a function of output Fig 7. power; typical values

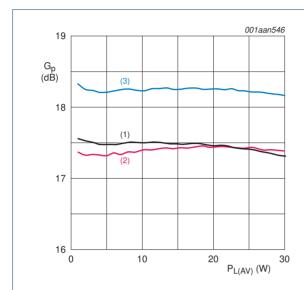


- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Pulsed CW drain efficiency as a function of Fig 8. output power; typical values

## 7.4 Single carrier W-CDMA

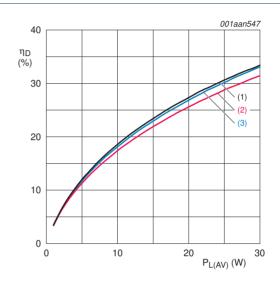
3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

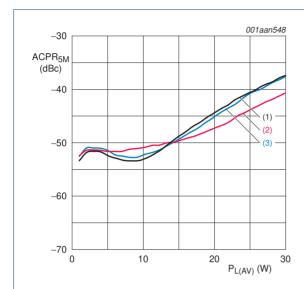
Fig 9. Single carrier W-CDMA power gain as a function of average output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Da} = 900 \text{ mA}.$ 

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

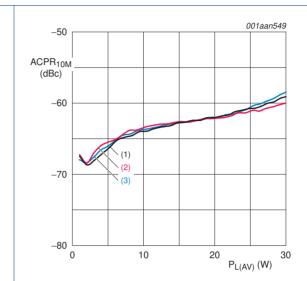
Fig 10. Single carrier W-CDMA drain efficiency as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

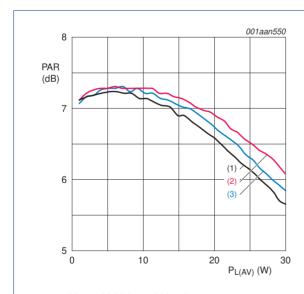
Fig 11. Single carrier W-CDMA ACPR at 5 MHz as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

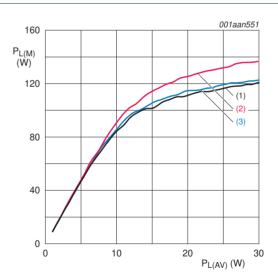
Fig 12. Single carrier W-CDMA ACPR at 10 MHz as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Fig 13. Single carrier W-CDMA peak-to-average power ratio as a function of average output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2500 MHz
- (2) f = 2600 MHz
- (3) f = 2700 MHz

Fig 14. Single carrier W-CDMA peak output power as a function of average output power; typical values

## Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

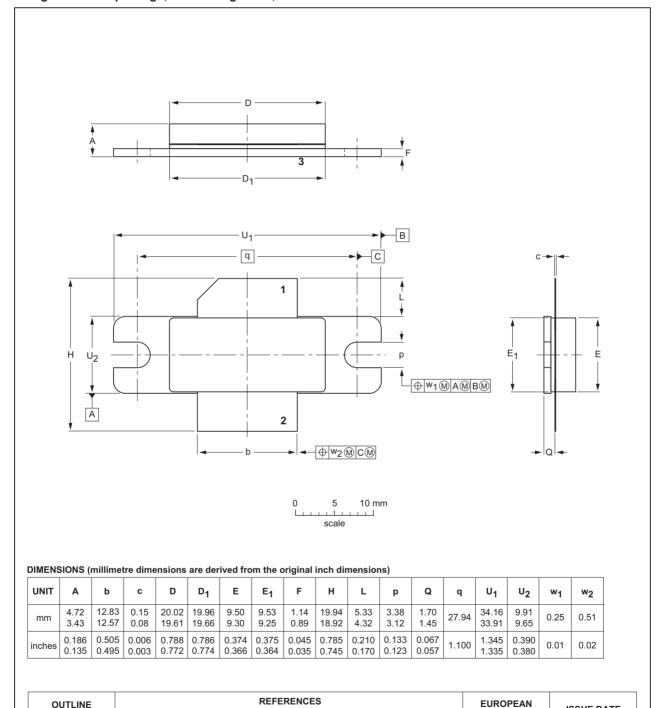


Fig 15. Package outline SOT502A

IEC

**JEDEC** 

OUTLINE

VERSION

SOT502A

JEITA

**ISSUE DATE** 

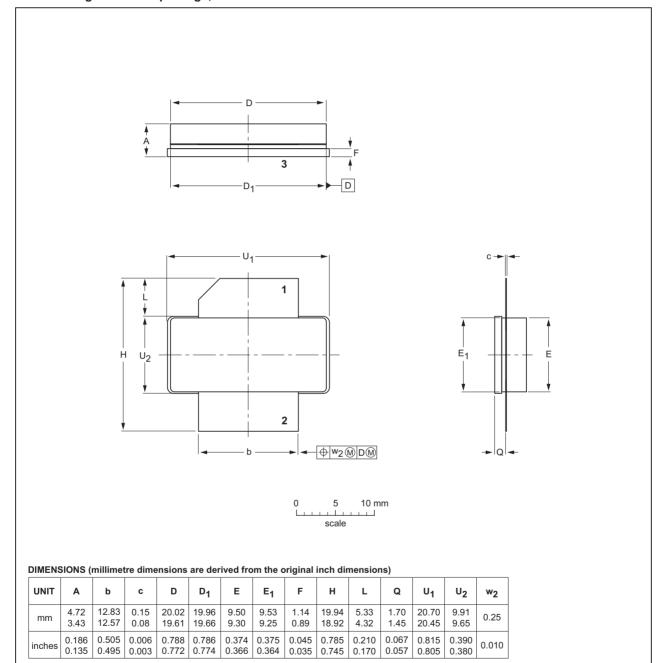
<del>-03-01-10</del>

12-05-02

**PROJECTION** 

#### Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE	
SOT502B					<del>-07-05-09</del> 12-05-02	

Fig 16. Package outline SOT502B

## 9. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 8. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	3A [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 3A is granted to any part that passes after exposure to an ESD pulse of 4000 V, but fails after exposure to an ESD pulse of 8000 V.

#### 10. Abbreviations

Table 9. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
IS-95	Interim Standard 95
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio

## 11. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF7G27L-100_7G27LS-100 v.5	20161201	Product data sheet	-	BLF7G27L-100_7G27LS-100 v.4
Modifications:	Section 9 on page 11: updated Handling information			
BLF7G27L-100_7G27LS-100 v.4	20150901	Product data sheet	-	BLF7G27L-100_7G27LS-100 v.3
BLF7G27L-100_7G27LS-100 v.3	20110722	Product data sheet	-	BLF7G27L-100_7G27LS-100 v.2
BLF7G27L-100_7G27LS-100 v.2	20110405	Preliminary data sheet	-	BLF7G27L-100_7G27LS-100 v.1
BLF7G27L-100_7G27LS-100 v.1	20100421	Objective data sheet	-	-

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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BLF7G27L-100 7G27LS-100

# BLF7G27L-100; BLF7G27LS-100

#### **Power LDMOS transistor**

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For sales office addresses, please visit: http://www.ampleon.com/sales

# BLF7G27L-100; BLF7G27LS-100

## **AMPLEON**

**Power LDMOS transistor** 

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